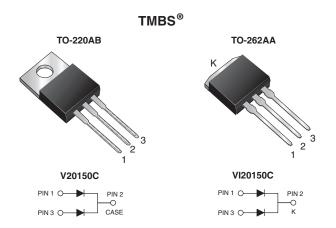
RoHS COMPLIANT

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.59$ V at $I_F = 5$ A



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PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _{RRM}	150 V				
I _{FSM}	120 A				
V_F at $I_F = 10$ A	0.69 V				
T _J max.	150 °C				
Package	TO-220AB, TO-262AA				
Diode variations	Common cathode				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- HALOGEN Solder dip 275 °C max. 10 s, per JESD 22-B106 FREE
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	V20150C	VI20150C	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	150		V		
Maximum average forward rectified current (fig. 1)	per device	I	20		А		
	per diode	IF(AV)	10				
Peak forward surge current 8.3 ms single half sine-w superimposed on rated load per diode	I _{FSM}	120		А			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150		°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.79	-	V	
	I _F = 10 A			1.05	1.20		
	I _F = 5 A	- T _A = 125 °C		0.59	-		
	I _F = 10 A			0.69	0.75		
Reverse current per diode	V _R = 100 V	T _A = 25 °C	I _R (2)	1.3	-	μA	
		T _A = 125 °C		1.2	-	mA	
	$V_{\rm D} = 150 V$	T _A = 25 °C		-	150	μA	
		T _A = 125 °C		3	15	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V20150C	VI20150C	UNIT	
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	2.8		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V20150C-M3/4W	1.88	4W	50/tube	Tube		
TO-262AA	VI20150C-M3/4W	1.45	4W	50/tube	Tube		



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

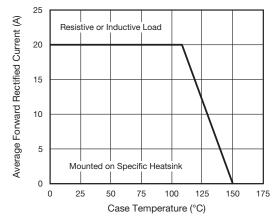


Fig. 1 - Maximum Forward Current Derating Curve

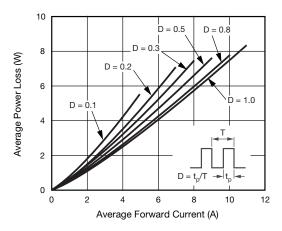


Fig. 2 - Forward Power Loss Characteristics Per Diode

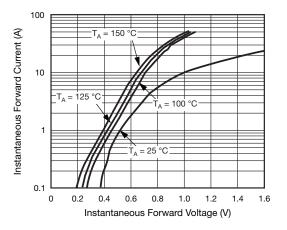


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

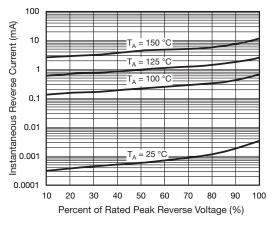


Fig. 4 - Typical Reverse Characteristics Per Diode

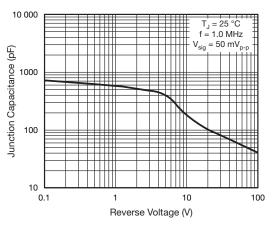


Fig. 5 - Typical Junction Capacitance Per Diode

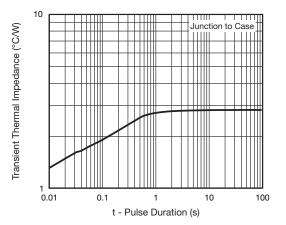


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Revision: 09-Nov-17

3

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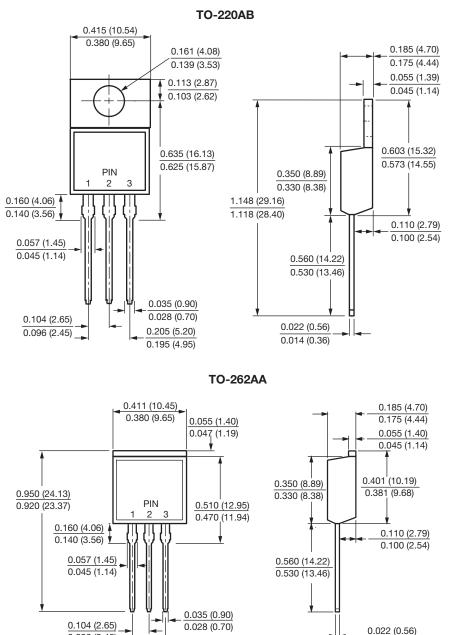
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0.014 (0.35)



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

0.096 (2.45)



0.205 (5.20)

0.195 (4.95)



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